

Flux Gate Current Sensor DXE2000-M6/61 I_{P N} = 2000 A

The DXE2000-M6/61 is a advanced flux gate current sensor that use high technology to bring the best combination of performance and reliability. It is rated for a primary current measurement range of ± 2000 A dc. It is calibrated and temperature compensated for improved accuracy using multi-point temperature characterization.

DIFFERENTIATION

• Accuracy: Multi-point temperature characterization and calibration for improved accuracy over temperature range.

• Magnetic immunity: Flux gate configuration and optimized magnetic circuit allow for excellent performance in diverse magnetic environments.

• Flexible: Customizable on-board firmware to meet specific application requirements.

Features

- Excellent accuracy
- Very good linearity
- Low temperature drift
- Wide frequency bandwidth
- Optimized response time

Application Domain

- Metrological verification and calibration
- Laboratory current measurement
- Instrumentation (e.g. power analyzer)
- Medical equipment, such as magnetic resonance imaging (MRI)
- Battery pack detection
- Power control





Electrical data

Parameter	Minimum value	Standard value	Maximum value	Condition	
Rated input current IPN=		±2000 Adc		/	
Measure range IPM=			±2200 Adc	1Min/Hour	
Power supply voltage Vc	±14 Vdc		±16 Vdc	Full range	
Current consumption I_{C}	±60 mA	±860 mA	±940 mA	I _{PM} range	
Current change K _N		Input : Output			
Rated output current IsN		800 mA		Rated input current	
Measuring resistance RM		3 Ω	4Ω		

Accuracy- Dynamic Parameter

Droject	Symbol	Test conditions	Numerical value		lue	Unit	
Project	Project Symbol		minimum	standard	maximum		
A	Xe	@0%~25%Ipn			0.005	A %RD	
Accuracy	Ae	@25%Ірм~Ірм			0.001		
Ratio error	X _{Ge} -	@0%~25%Ipn			0.005	A	
		@25%Ірл~Ірм			0.001	%RD	
angle error	XPe				0.01	crad	
Linearity	٤L				5	ppm	
Temperature drift coefficient	TCI				0.2	ppm/K	
Time drift coefficient	тт				0.5	ppm/month	
Power supply anti-interference	TV				1	ppm/V	
Zero offset current	lo	25±10 ℃			±0.002	mA	
Zero offset current	Іот	Within the full operating temperature range			±0.005	mA	
Ripple current	In	DC-10Hz			1	ppm	
Dynamic response time	_	di/dt=100A/us					
	Tr	rise to 90% IPN			1	us	
Current following speed	di/dt		100			A/us	
Bandwidth(- 3 dB)	F		0		100	kHz	



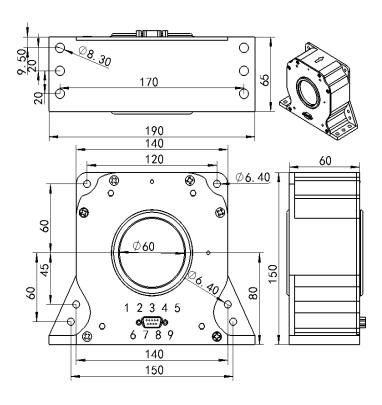
General characteristics

Project	Symbol	Toot conditions	Numerical value		Unit	
	Symbol	Test conditions minimum standar	standard	maximum	Unit	
Operating temperature range	TA		-40		85	°C
Storage Temperature Range	Ts		-45		85	°C
Weight	m		3000g±500g			g

Safety characteristics

Project		Symbol	Test Numerical value			lue	Unit	
		e y me er	conditions	minimum	standard	maximum	C'III	
Withstand voltage	Between primary and secondary edges	Vd	50Hz,1min		2.5		KV	
Transient isolation withstand voltage	Between primary and secondary edges	Vw	50us		5		ΚV	

Mechanical dimension (mm)



Pin Definition

Pin number	Pin Definition		
1	GND		
2	NC		
3	GND		
4	GND		
5	-VCC		
6	Output		
7	NC		
8	Effective		
0	indication		
9	+VCC		



Mechanical characteristics

- General tolerance: ± 1mm
- Connector: DB9

NOTE

• When the direction of the input current IP is consistent with the direction indicated by the arrow in the outline drawing, the output current IS is in the forward direction.

• Please try to locate the primary conductor at the center of the probe aperture as much as possible.

• The through-hole is made of metal material, so the through-hole wire cannot be an exposed cable. The through-hole wire must be insulated.

- This module is a standard sensor, please contact us for special applications.
- We reserve the right to modify this sensor manual without prior notice.